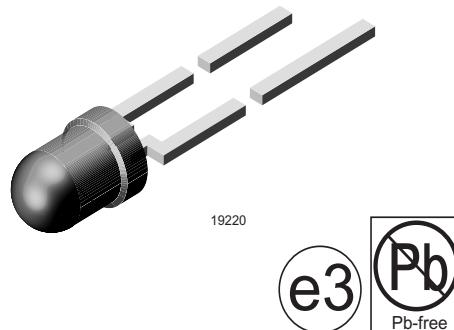


Low Current LED in Ø 3 mm Tinted Diffused Package

Features

- Low power consumption
- High brightness
- CMOS/MOS compatible
- Specified at $I_F = 2 \text{ mA}$
- Luminous intensity categorized
- Yellow and green color categorized
- Lead-free device



Applications

Low power DC circuits

Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ($\pm\phi$)	Technology
TLLR4400	Red, $I_V > 0.63 \text{ mcd}$	25 °	GaAsP on GaP
TLLR4401	Red, $I_V > 1 \text{ mcd}$	25 °	GaAsP on GaP
TLLY4400	Yellow, $I_V > 0.63 \text{ mcd}$	25 °	GaAsP on GaP
TLLY4401	Yellow, $I_V > 1 \text{ mcd}$	25 °	GaAsP on GaP
TLLG4400	Green, $I_V > 0.63 \text{ mcd}$	25 °	GaP on GaP
TLLG4401	Green, $I_V > 1 \text{ mcd}$	25 °	GaP on GaP

Absolute Maximum Ratings

$T_{amb} = 25 \text{ }^{\circ}\text{C}$, unless otherwise specified

TLL.440.

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V_R	6	V
DC Forward current		I_F	7	mA
Surge forward current	$t_p \leq 10 \mu\text{s}$	I_{FSM}	0.15	A
Power dissipation	$T_{amb} \leq 84 \text{ }^{\circ}\text{C}$	P_V	20	mW
Junction temperature		T_j	100	$^{\circ}\text{C}$
Operating temperature range		T_{amb}	- 40 to + 100	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$, 2 mm from body	T_{sd}	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient		R_{thJA}	800	K/W

Optical and Electrical CharacteristicsT_{amb} = 25 °C, unless otherwise specified**Red****TLLR440.**

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	I _F = 2 mA	TLLR4400	I _V	0.63	1.2		mcd
		TLLR4401	I _V	1	2		mcd
Dominant wavelength	I _F = 2 mA		λ _d	612		625	nm
Peak wavelength	I _F = 2 mA		λ _p		635		nm
Angle of half intensity	I _F = 2 mA		φ		± 25		deg
Forward voltage	I _F = 2 mA		V _F		1.9	2.4	V
Reverse voltage	I _R = 10 µA		V _R	6	20		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

¹⁾ in one Packing Unit I_{Vmin}/I_{Vmax} ≤ 0.5**Yellow****TLLY440.**

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	I _F = 2 mA	TLLY4400	I _V	0.63	1.2		mcd
		TLLY4401	I _V	1	2		mcd
Dominant wavelength	I _F = 2 mA		λ _d	581		594	nm
Peak wavelength	I _F = 2 mA		λ _p		585		nm
Angle of half intensity	I _F = 2 mA		φ		± 25		deg
Forward voltage	I _F = 2 mA		V _F		2.4	2.9	V
Reverse voltage	I _R = 10 µA		V _R	6	20		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

¹⁾ in one Packing Unit I_{Vmin}/I_{Vmax} ≤ 0.5**Green****TLLG440.**

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Luminous intensity ¹⁾	I _F = 2 mA	TLLG4400	I _V	0.63	1.2		mcd
		TLLG4401	I _V	1	2		mcd
Dominant wavelength	I _F = 2 mA		λ _d	562		575	nm
Peak wavelength	I _F = 2 mA		λ _p		565		nm
Angle of half intensity	I _F = 2 mA		φ		± 25		deg
Forward voltage	I _F = 2 mA		V _F		1.9	2.4	V
Reverse voltage	I _R = 10 µA		V _R	6	20		V
Junction capacitance	V _R = 0, f = 1 MHz		C _j		50		pF

¹⁾ in one Packing Unit I_{Vmin}/I_{Vmax} ≤ 0.5

Package Dimensions in mm

